

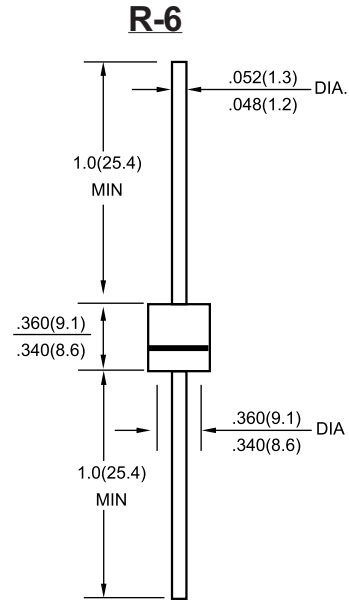


### FEATURES

- Metal of silicon rectifier , majority carrier conduction
- Guard ring for transient protection
- Low power loss,high efficiency
- High current capability,low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage,high frequency inverters,free wheeling,and polarity protection applications

### MECHANICAL DATA

- Case: JEDEC R-6 molded plastic
- Polarity: Color band denotes cathode
- Weight: 0.07 ounces , 2.1 grams
- Mounting position: Any



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

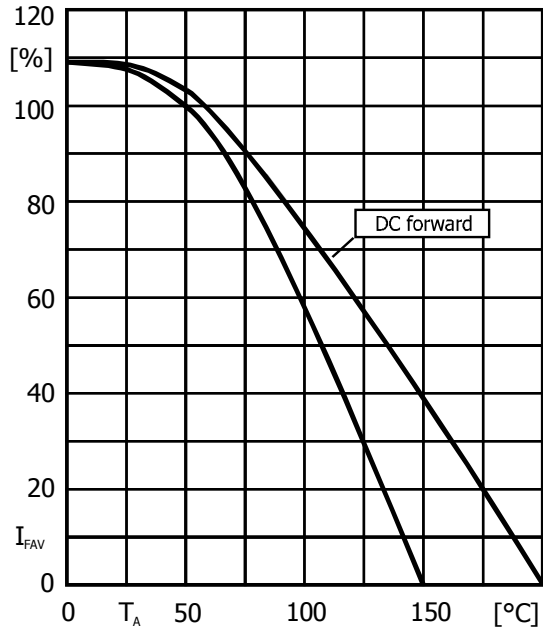
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	10SQ030	10SQ035	10SQ040	10SQ045	10SQ050	10SQ060	10SQ080	10SQ100	UNIT	
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	30	35	40	45	50	60	80	100	V	
Maximum RMS Voltage	V <sub>RMS</sub>	21	24.5	28	31.5	35	42	56	70	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	30	35	40	45	50	60	80	100	V	
Maximum Average Forward Rectified Current@T <sub>c</sub> =95 °C	I <sub>(AV)</sub>	10								A	
Peak Forward Surage Current 8.3ms single half sine-wave super imposed on rated load(JEDEC Method)	I <sub>FSM</sub>	275								A	
Peak Forward Voltage at 10A DC(Note1)	V <sub>F</sub>	0.55			0.7		0.8			V	
Maximum DC Reverse Current @T <sub>j</sub> =25°C at Rated DC Bolcking Voltage @T <sub>j</sub> =125°C	I <sub>R</sub>	0.1				50					mA
Typical Junction Capacitance (Note2)	C <sub>J</sub>	450									PF
Typical Thermal Resistance (Note3)	R <sub>θJC</sub>	3.0									°C/w
Junction temperature Range in DC forward mode	T <sub>J</sub>	-55 to+200									°C
Storage Temperature Range	T <sub>S</sub>	-55 to+175									°C
ESD	VESD	15000									V

NOTES:1.300us Pulse Width, 2%Dudy Cycle.

2.Measured at 1.0 MHZ and applied reverse voltage of 4.0VDC.

3.Thermal Resistance Junction to Case.



Rated forward current versus ambient temperature<sup>1)</sup>  
Zul. Richtstrom in Abh. von der Umgebungstemp.<sup>1)</sup>

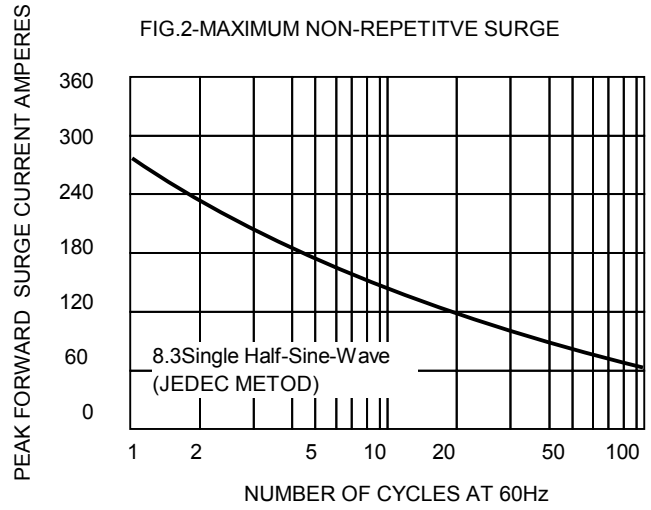


FIG.3-TYPICAL REVERSE CHARACTERISTICS

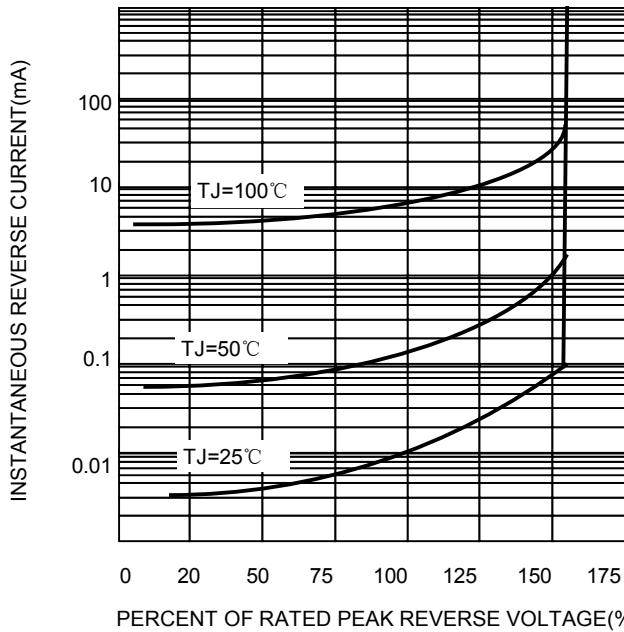


FIG.4-TYPICAL FORWARD CHARACTERISTICS

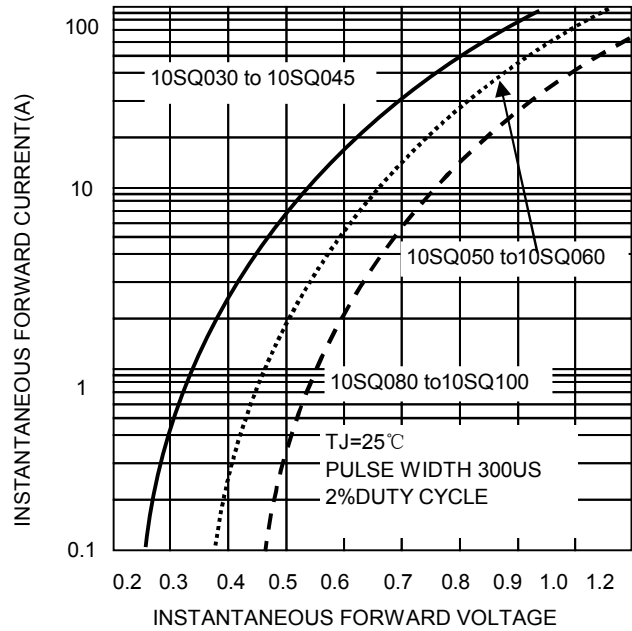


FIG.5-TYPICAL JUNCTION CAPACITANCE

